



IXTP08N100D2 Information



For Reference Only

Part Number IXTP08N100D2

Manufacturer IXYS

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 1000V 0.8A TO220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IXTP08N100D2 Specifications

Manufacturer Part Number	IXTP08N100D2
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	1000V
Current - Continuous Drain (Id) @ 25°C	800mA (Tc)
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	14.6nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	325pF @ 25V
Vgs (Max)	±20V
FET Feature	Depletion Mode
Power Dissipation (Max)	60W (Tc)
Rds On (Max) @ Id, Vgs	21 Ohm @ 400mA, 0V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IXTP08N100D2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTP08N100D2 Payment Methods



















IXTP08N100D2 Shipping Methods













If you have any question about IXTP08N100D2, please do not hesitate to contact us!

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